



# PSMN6R9-100YSF

NextPower 100 V, 7 mΩ N-channel MOSFET in LPAK56 package

8 December 2017

Product data sheet

## 1. General description

NextPower 100 V standard level gate drive MOSFET. Qualified to 175 °C and recommended for industrial & consumer applications.

## 2. Features and benefits

- Low  $Q_{rr}$  for higher efficiency and lower spiking
- Qualified to 175 °C
- Low  $Q_G \times R_{DS(on)}$  FOM for high efficiency switching applications
- Strong avalanche energy rating ( $E_{as}$ )
- Avalanche rated and 100% tested
- Ha-free and RoHS compliant LPAK56 package
- Wave-solderable LPAK56 package

## 3. Applications

- Synchronous rectifier in AC-DC and DC-DC
- BLDC motor control
- USB-PD and mobile fast-charge adapters
- LED lighting
- Full-bridge and half-bridge applications
- Flyback and resonant topologies

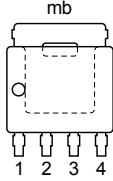
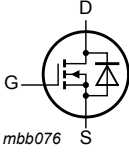
## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{DS}$	drain-source voltage	$25\text{ °C} \leq T_j \leq 175\text{ °C}$	-	-	100	V
$I_D$	drain current	$V_{GS} = 10\text{ V}$ ; $T_{mb} = 25\text{ °C}$ ; <a href="#">Fig. 2</a>	-	-	90	A
$P_{tot}$	total power dissipation	$T_{mb} = 25\text{ °C}$ ; <a href="#">Fig. 1</a>	-	-	238	W
<b>Static characteristics</b>						
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = 10\text{ V}$ ; $I_D = 25\text{ A}$ ; $T_j = 25\text{ °C}$ ; <a href="#">Fig. 10</a>	-	5.6	7	mΩ
<b>Dynamic characteristics</b>						
$Q_{GD}$	gate-drain charge	$I_D = 25\text{ A}$ ; $V_{DS} = 50\text{ V}$ ; $V_{GS} = 10\text{ V}$ ; <a href="#">Fig. 12</a> ; <a href="#">Fig. 13</a>	-	10.3	-	nC
<b>Source-drain diode</b>						
$Q_r$	recovered charge	$I_S = 25\text{ A}$ ; $di_S/dt = -100\text{ A/}\mu\text{s}$ ; $V_{GS} = 0\text{ V}$ ; $V_{DS} = 50\text{ V}$ ; <a href="#">Fig. 16</a>	-	52.4	-	nC

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	 <p><b>LPAK56; Power-SO8 (SOT669)</b></p>	 <p>mbb076</p>
2	S	source		
3	S	source		
4	G	gate		
mb	D	mounting base; connected to drain		

## 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PSMN6R9-100YSF	LPAK56; Power-SO8	Plastic single-ended surface-mounted package (LPAK56; Power-SO8); 4 leads	SOT669

## 7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN6R9-100YSF	6F9S10

## 8. Limiting values

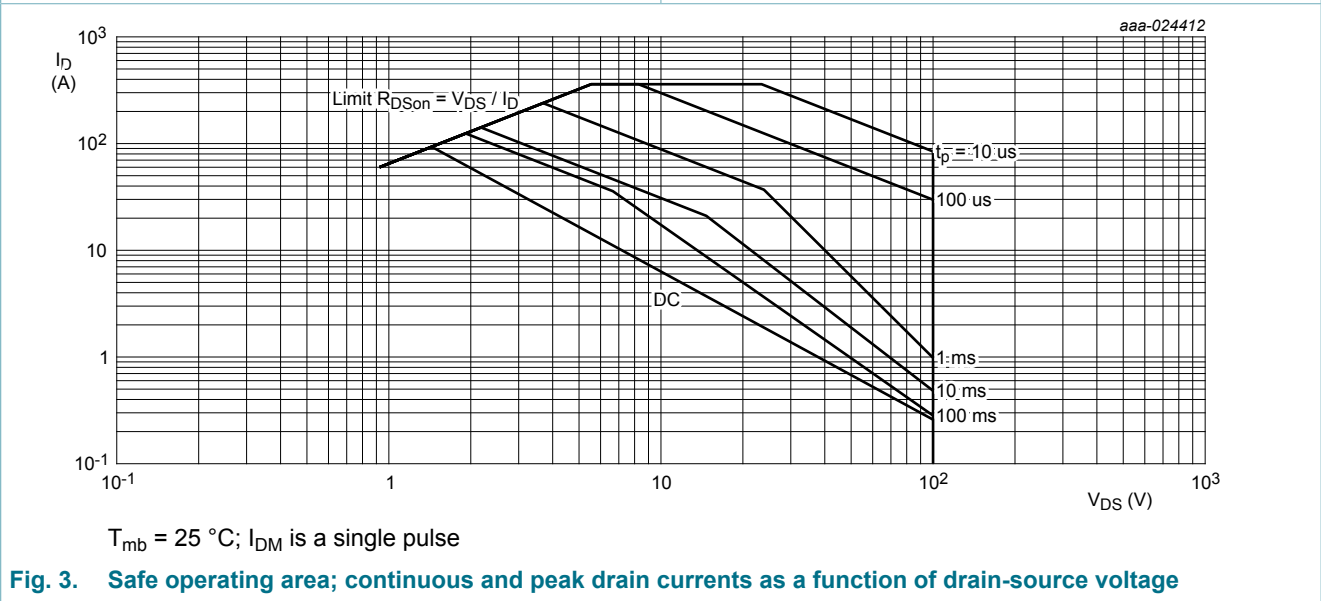
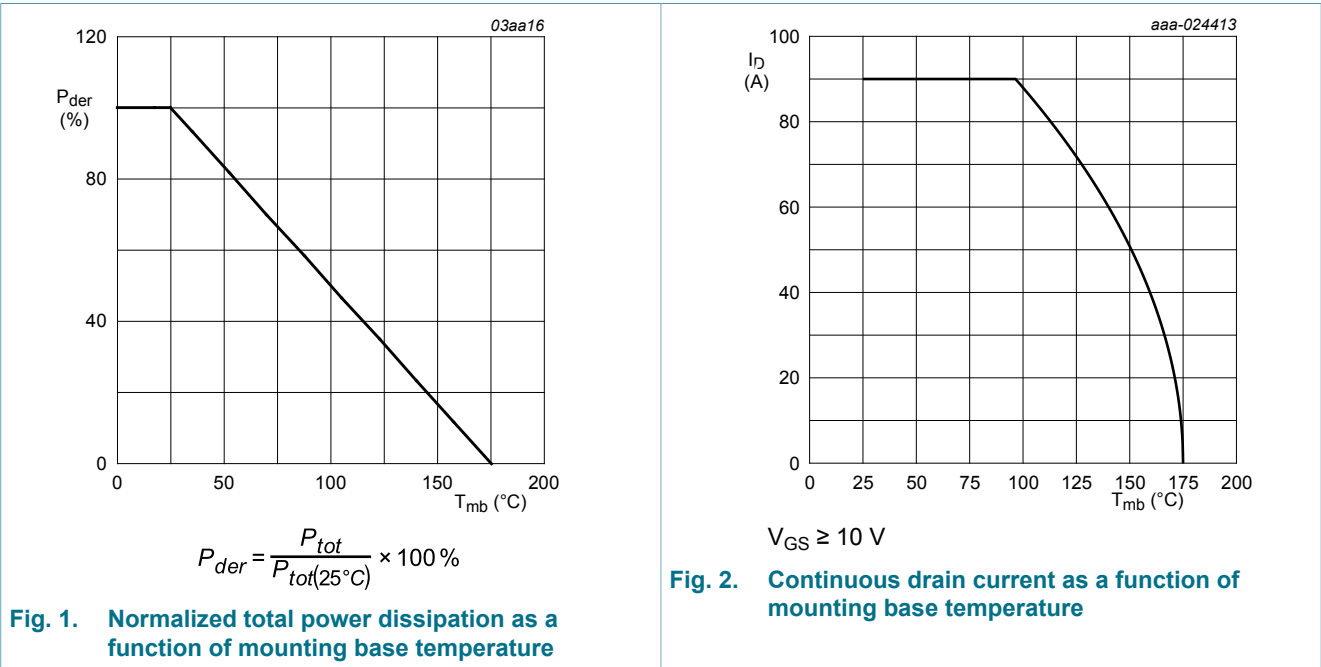
Table 5. Limiting values

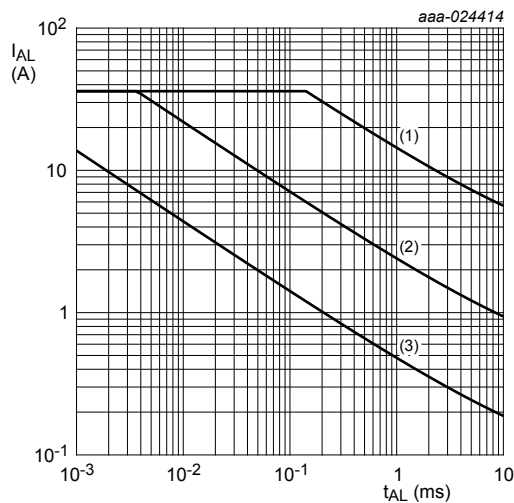
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage	$25\text{ °C} \leq T_j \leq 175\text{ °C}$	-	100	V
$V_{DGR}$	drain-gate voltage	$25\text{ °C} \leq T_j \leq 175\text{ °C}$ ; $R_{GS} = 20\text{ k}\Omega$	-	100	V
$V_{GS}$	gate-source voltage		-20	20	V
$P_{tot}$	total power dissipation	$T_{mb} = 25\text{ °C}$ ; <a href="#">Fig. 1</a>	-	238	W
$I_D$	drain current	$V_{GS} = 10\text{ V}$ ; $T_{mb} = 25\text{ °C}$ ; <a href="#">Fig. 2</a>	-	90	A
		$V_{GS} = 10\text{ V}$ ; $T_{mb} = 100\text{ °C}$ ; <a href="#">Fig. 2</a>	-	88	A
$I_{DM}$	peak drain current	pulsed; $t_p \leq 10\text{ }\mu\text{s}$ ; $T_{mb} = 25\text{ °C}$ ; <a href="#">Fig. 3</a>	-	360	A
$T_{stg}$	storage temperature		-55	175	°C
$T_j$	junction temperature		-55	175	°C
$T_{sld(M)}$	peak soldering temperature		-	260	°C

Symbol	Parameter	Conditions		Min	Max	Unit
Source-drain diode						
I <sub>S</sub>	source current	T <sub>mb</sub> = 25 °C		-	90	A
I <sub>SM</sub>	peak source current	pulsed; t <sub>p</sub> ≤ 10 μs; T <sub>mb</sub> = 25 °C		-	360	A
Avalanche ruggedness						
E <sub>DS(AL)S</sub>	non-repetitive drain-source avalanche energy	I <sub>D</sub> = 36 A; V <sub>sup</sub> ≤ 100 V; R <sub>GS</sub> = 50 Ω; V <sub>GS</sub> = 10 V; T <sub>j(init)</sub> = 25 °C; Fig. 4; Unclamped	[1]	-	321	mJ
I <sub>AS</sub>	non-repetitive avalanche current	V <sub>sup</sub> ≤ 100 V; V <sub>GS</sub> = 10 V; T <sub>j(init)</sub> = 25 °C; R <sub>GS</sub> = 50 Ω	[1]	-	36	A

[1] Protected by 100% test





(1)  $T_{j\text{ (init)}} = 25\text{ }^{\circ}\text{C}$ ; (2)  $T_{j\text{ (init)}} = 150\text{ }^{\circ}\text{C}$ ; (3) Repetitive Avalanche

Fig. 4. Avalanche rating; avalanche current as a function of avalanche time

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 5	-	0.56	0.63	K/W

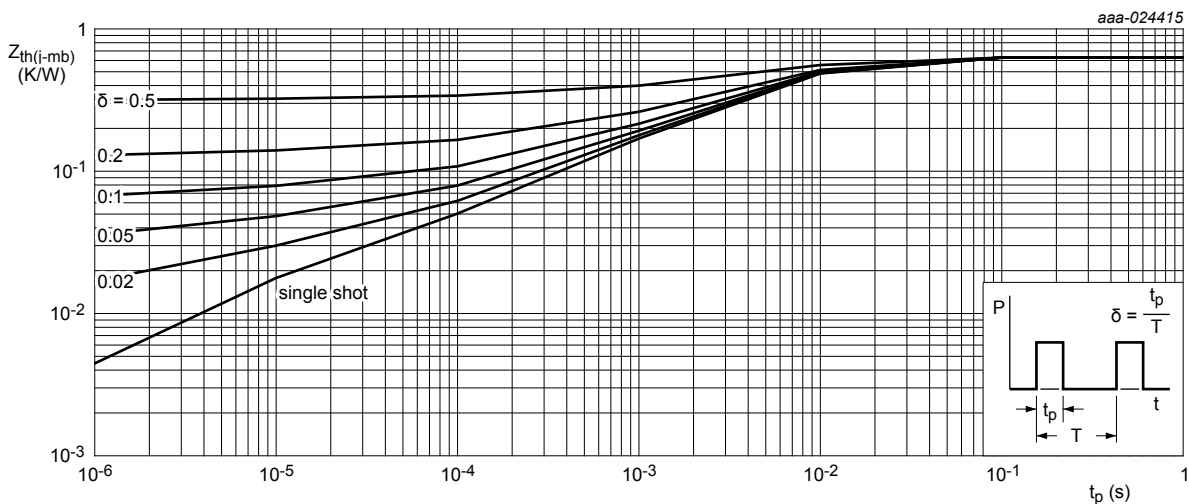


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

## 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250\ \mu\text{A}$ ; $V_{GS} = 0\ \text{V}$ ; $T_j = 25\ ^\circ\text{C}$	100	-	-	V
		$I_D = 250\ \mu\text{A}$ ; $V_{GS} = 0\ \text{V}$ ; $T_j = -55\ ^\circ\text{C}$	90	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1\ \text{mA}$ ; $V_{DS}=V_{GS}$ ; $T_j = -55\ ^\circ\text{C}$	-	3.7	-	V
		$I_D = 1\ \text{mA}$ ; $V_{DS}=V_{GS}$ ; $T_j = 175\ ^\circ\text{C}$	-	2	-	V
		$I_D = 1\ \text{mA}$ ; $V_{DS}=V_{GS}$ ; $T_j = 25\ ^\circ\text{C}$ ; <a href="#">Fig. 9</a>	2	3.3	4	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature	$25\ ^\circ\text{C} \leq T_j \leq 175\ ^\circ\text{C}$	-	-8.4	-	mV/K
$I_{DSS}$	drain leakage current	$V_{DS} = 100\ \text{V}$ ; $V_{GS} = 0\ \text{V}$ ; $T_j = 25\ ^\circ\text{C}$	-	0.02	5	$\mu\text{A}$
		$V_{DS} = 100\ \text{V}$ ; $V_{GS} = 0\ \text{V}$ ; $T_j = 125\ ^\circ\text{C}$	-	-	100	$\mu\text{A}$
$I_{GSS}$	gate leakage current	$V_{GS} = -20\ \text{V}$ ; $V_{DS} = 0\ \text{V}$ ; $T_j = 25\ ^\circ\text{C}$	-	5	100	nA
		$V_{GS} = 20\ \text{V}$ ; $V_{DS} = 0\ \text{V}$ ; $T_j = 25\ ^\circ\text{C}$	-	5	100	nA
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = 10\ \text{V}$ ; $I_D = 25\ \text{A}$ ; $T_j = 25\ ^\circ\text{C}$ ; <a href="#">Fig. 10</a>	-	5.6	7	mΩ
		$V_{GS} = 7\ \text{V}$ ; $I_D = 25\ \text{A}$ ; $T_j = 25\ ^\circ\text{C}$ ; <a href="#">Fig. 10</a>	-	6.6	10.2	mΩ
		$V_{GS} = 10\ \text{V}$ ; $I_D = 25\ \text{A}$ ; $T_j = 100\ ^\circ\text{C}$ ; <a href="#">Fig. 11</a>	-	8.9	10.9	mΩ
		$V_{GS} = 10\ \text{V}$ ; $I_D = 25\ \text{A}$ ; $T_j = 175\ ^\circ\text{C}$ ; <a href="#">Fig. 11</a>	-	12.5	15.4	mΩ
$R_G$	gate resistance	$f = 1\ \text{MHz}$	-	0.9	-	Ω
<b>Dynamic characteristics</b>						
$Q_{G(tot)}$	total gate charge	$I_D = 25\ \text{A}$ ; $V_{DS} = 50\ \text{V}$ ; $V_{GS} = 10\ \text{V}$ ; <a href="#">Fig. 12</a> ; <a href="#">Fig. 13</a>	-	50.3	-	nC
		$I_D = 0\ \text{A}$ ; $V_{DS} = 0\ \text{V}$ ; $V_{GS} = 10\ \text{V}$	-	20.9	-	nC
$Q_{GS}$	gate-source charge	$I_D = 25\ \text{A}$ ; $V_{DS} = 50\ \text{V}$ ; $V_{GS} = 10\ \text{V}$ ; <a href="#">Fig. 12</a> ; <a href="#">Fig. 13</a>	-	17.1	-	nC
$Q_{GS(th)}$	pre-threshold gate-source charge		-	9.9	-	nC
$Q_{GS(th-pl)}$	post-threshold gate-source charge		-	7.2	-	nC
$Q_{GD}$	gate-drain charge		-	10.3	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	$I_D = 25\ \text{A}$ ; $V_{DS} = 50\ \text{V}$ ; <a href="#">Fig. 12</a> ; <a href="#">Fig. 13</a>	-	5.1	-	V
$C_{iss}$	input capacitance	$V_{DS} = 50\ \text{V}$ ; $V_{GS} = 0\ \text{V}$ ; $f = 1\ \text{MHz}$ ; $T_j = 25\ ^\circ\text{C}$ ; <a href="#">Fig. 14</a>	-	3570	-	pF
$C_{oss}$	output capacitance		-	722	-	pF
$C_{rss}$	reverse transfer capacitance		-	19	-	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 50\ \text{V}$ ; $R_L = 2\ \Omega$ ; $V_{GS} = 10\ \text{V}$ ; $R_{G(ext)} = 5\ \Omega$ ; $T_j = 25\ ^\circ\text{C}$	-	14.8	-	ns
$t_r$	rise time		-	14.2	-	ns

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
t <sub>d(off)</sub>	turn-off delay time			-	27.6	-	ns
t <sub>f</sub>	fall time			-	16	-	ns
Source-drain diode							
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 25 A; V <sub>GS</sub> = 0 V; T <sub>J</sub> = 25 °C; <a href="#">Fig. 15</a>		-	0.8	1.2	V
t <sub>rr</sub>	reverse recovery time	I <sub>S</sub> = 25 A; dI <sub>S</sub> /dt = -100 A/μs; V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 50 V; <a href="#">Fig. 16</a>		-	45.4	-	ns
Q <sub>r</sub>	recovered charge			-	52.4	-	nC

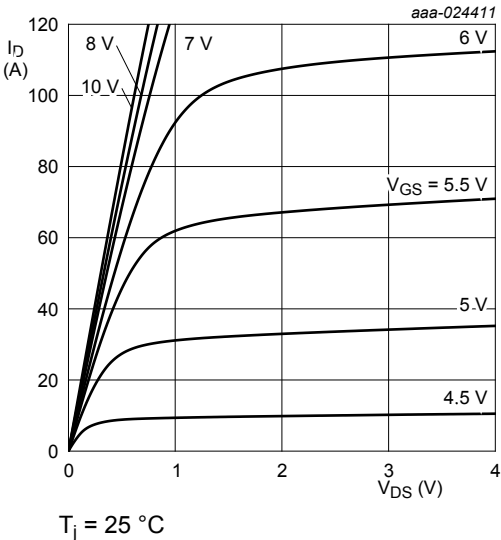


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

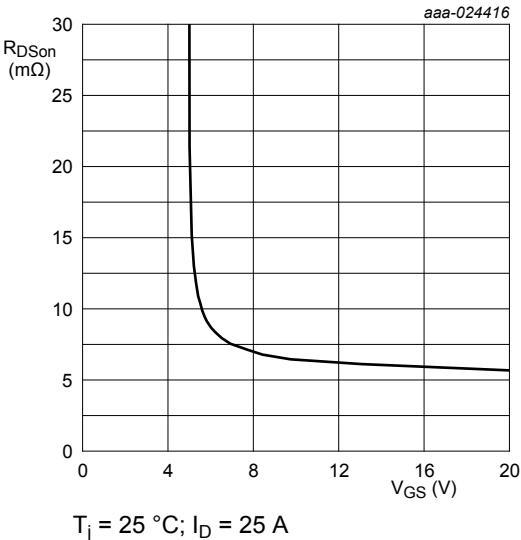


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

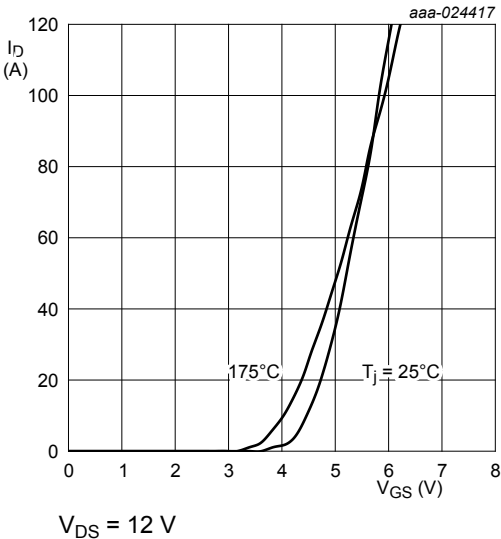


Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values

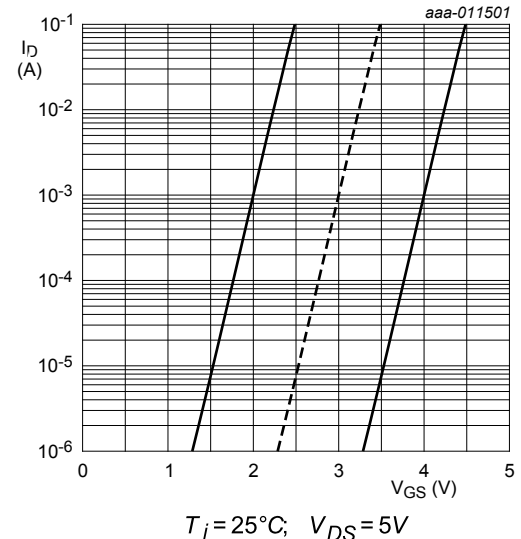


Fig. 9. Sub-threshold drain current as a function of gate-source voltage

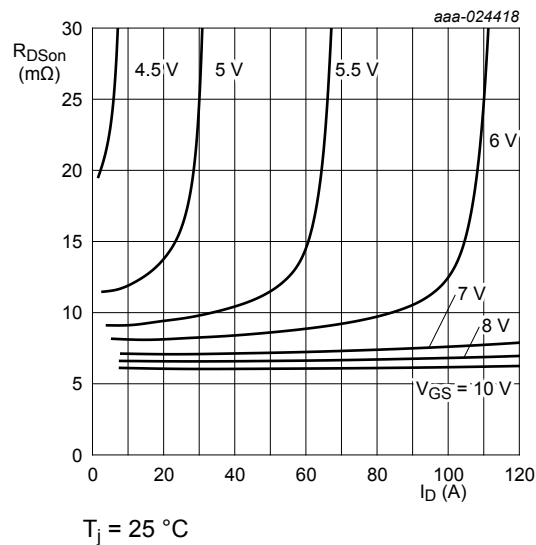


Fig. 10. Drain-source on-state resistance as a function of drain current; typical values

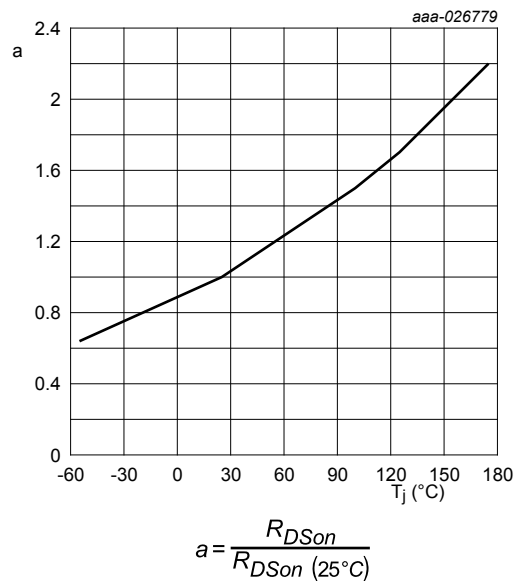


Fig. 11. Normalized drain-source on-state resistance factor as a function of junction temperature

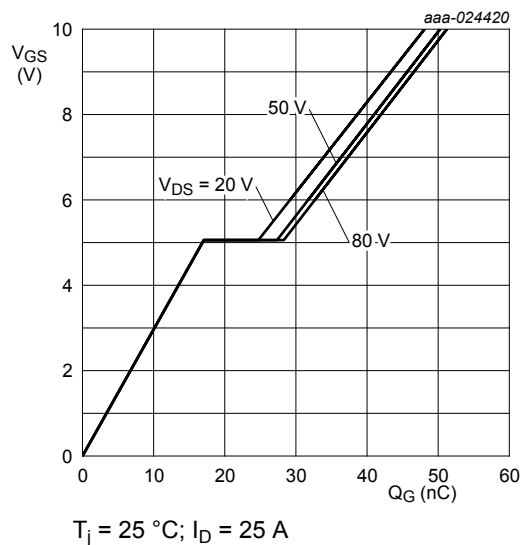


Fig. 12. Gate-source voltage as a function of gate charge; typical values

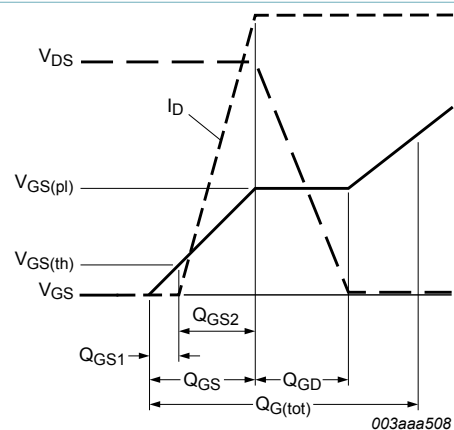


Fig. 13. Gate charge waveform definitions

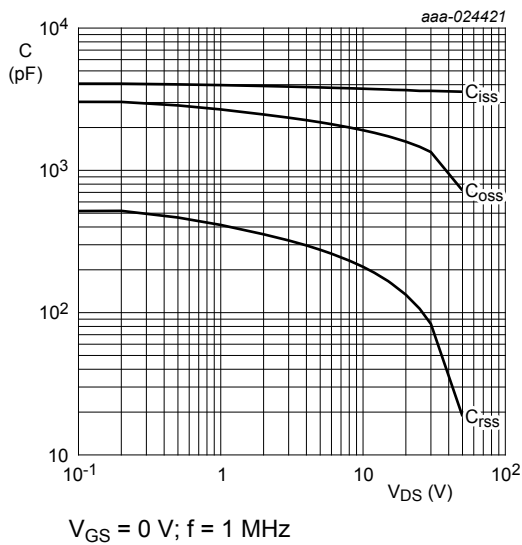


Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

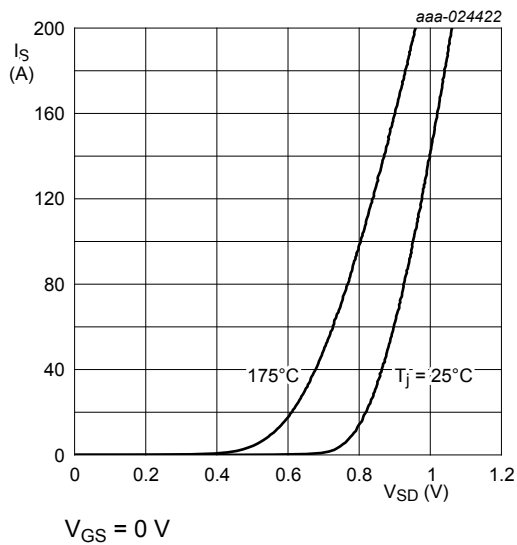


Fig. 15. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

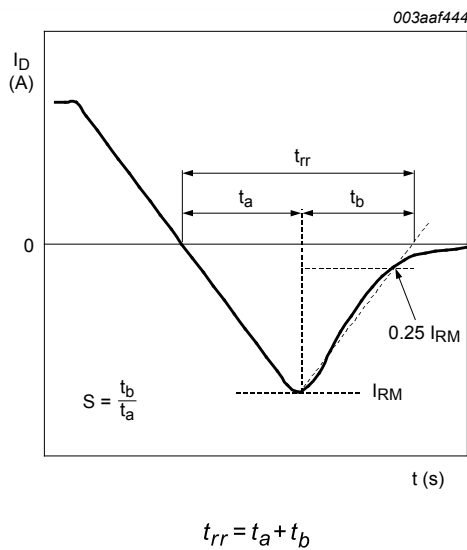


Fig. 16. Reverse recovery waveform definitions



11. Package outline

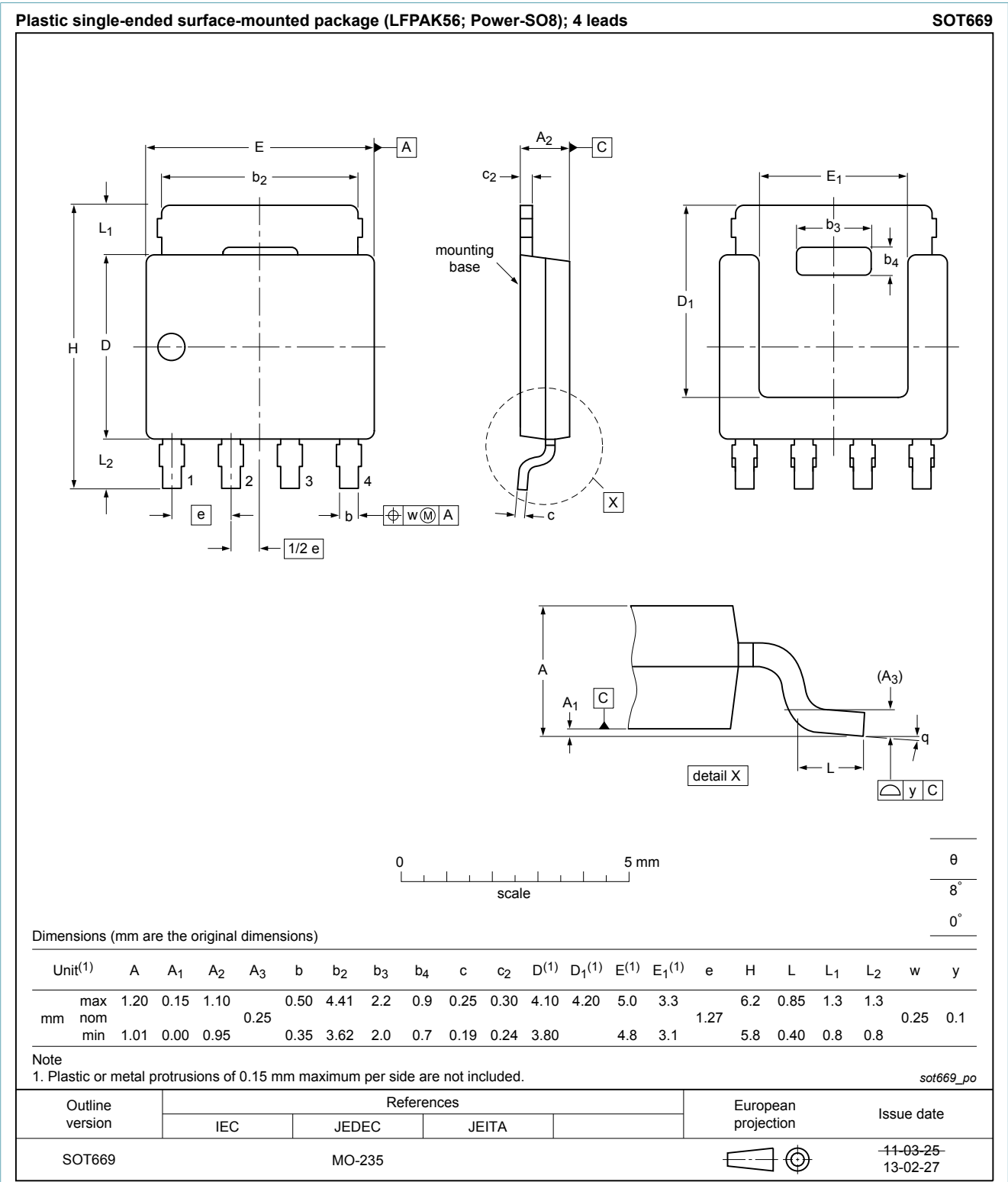


Fig. 17. Package outline LPAK56; Power-SO8 (SOT669)

12. Soldering

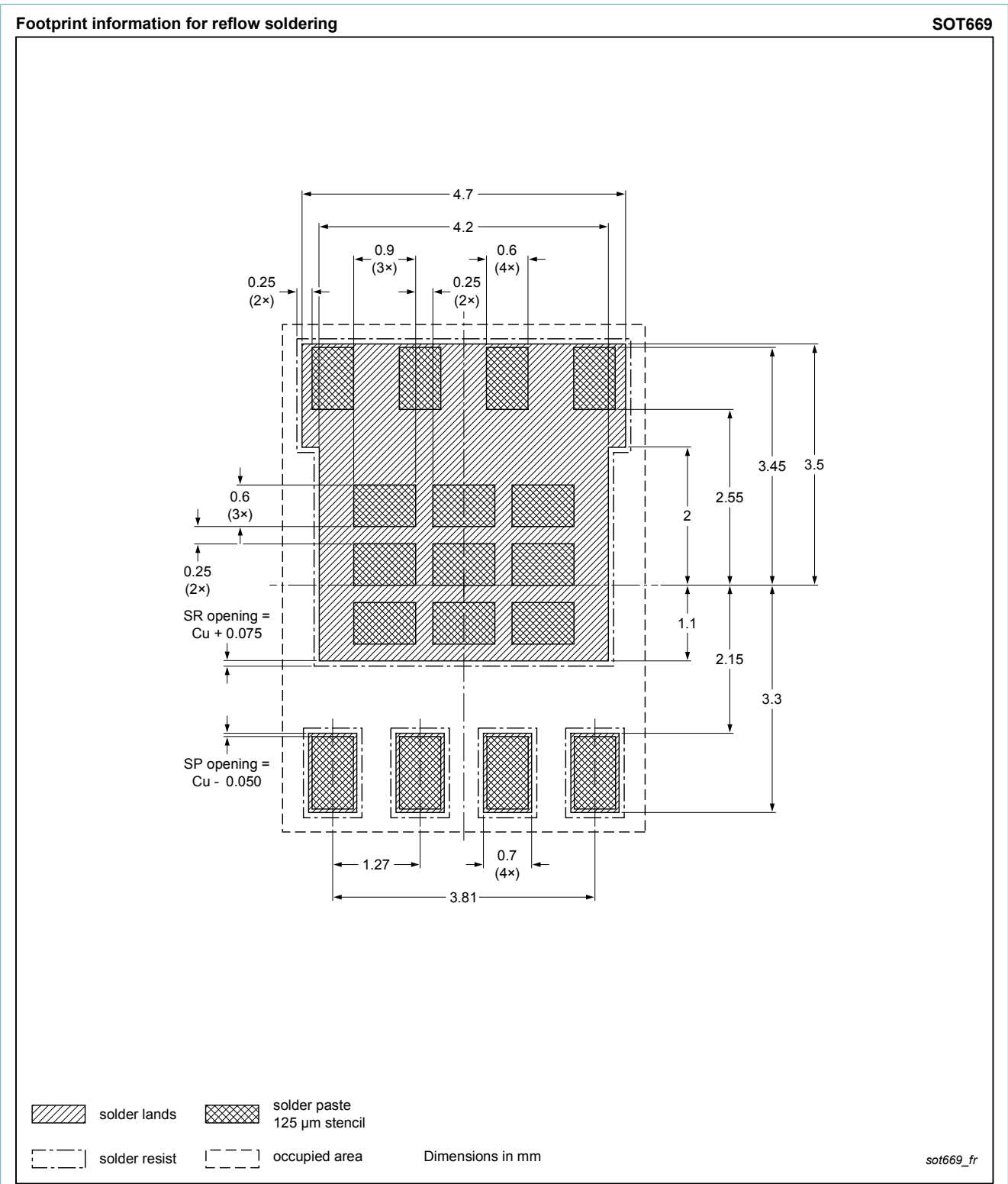


Fig. 18. Reflow soldering footprint for LPAK56; Power-SO8 (SOT669)

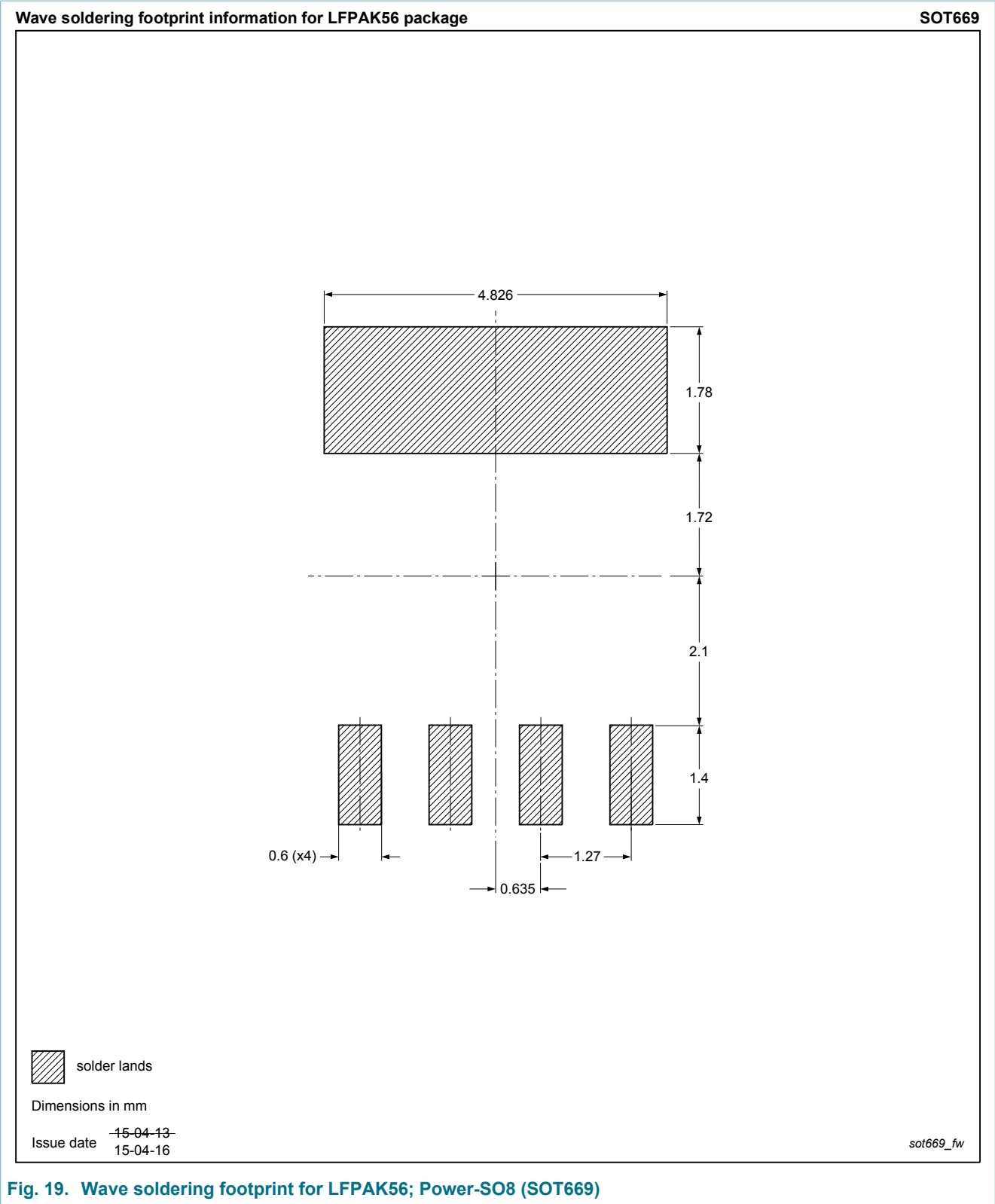


Fig. 19. Wave soldering footprint for LPAK56; Power-SO8 (SOT669)

## 13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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14. Contents

1. General description..... 1

2. Features and benefits..... 1

3. Applications..... 1

4. Quick reference data..... 1

5. Pinning information.....2

6. Ordering information.....2

7. Marking.....2

8. Limiting values..... 2

9. Thermal characteristics..... 4

10. Characteristics.....5

11. Package outline..... 9

12. Soldering..... 10

13. Legal information..... 12

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